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N**ational** Semiconductor

LMV1015 Analog Series: Built-in Gain IC's for High Sensitivity 2-Wire **Microphones General Description Features**

The LMV1015 is an audio amplifier series for small form factor electret microphones. This 2-wire portfolio is designed to replace the JFET amplifier. The LMV1015 series is ideally suited for applications requiring high signal integrity in the presence of ambient or RF noise, such as in cellular communications. The LMV1015 audio amplifiers are guaranteed to operate over a 2.2V to 5.0V supply voltage range with fixed gains of 15.6 dB and 23.8 dB. The devices offer excellent THD, gain accuracy and temperature stability as compared to a JFET microphone.

The LMV1015 series enables a two-pin electret microphone solution, which provides direct pin-to-pin compatibility with the existing older JFET market.

National Semiconductors built-in gain families are offered in extremely thin space saving 4-bump micro SMD packages (0.3 mm maximum). The LMV1015XR is designed for 1.0 mm ECM canisters and thicker. These extremely miniature packages have the Large Dome Bump (LDB) technology. This micro SMD technology is designed for microphone PCBs requiring 1 kg adhesion criteria.

(Typical LMV1015-15, 2.2V supply, $R_{L} = 2.2 \text{ k}\Omega$, $C = 2.2 \mu\text{F}$, $V_{IN} = 18 \text{ mV}_{PP}$, unless otherwise specified)

- 2V 5V Supply voltage Supply current <180 µA Signal to noise ratio (A-weighted) 60 dB -89 dBV
- Output voltage noise (A-weighted)
- Total harmonic distortion 0.09% Voltage gain
- LMV1015-15 15.6 dB
- LMV1015-25 23.8 dB Temperature range -40°C to 85°C
- Large Dome 4-Bump micro SMD package with improved adhesion technology.

Applications

- Cellular phones
- Headsets
- Mobile communications
- Automotive accessories
- PDAs
- Accessory microphone products



Built-In Gain Electret Microphone



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

| ESD Tolerance (Note 2) | |
|---------------------------|----------------|
| Human Body Model | 2500V |
| Machine Model | 250V |
| Supply Voltage | |
| V _{DD} - GND | 5.5V |
| Storage Temperature Range | –65°C to 150°C |

| Junction Temperature (Note 6) | 150°C max |
|----------------------------------|-----------|
| Mounting Temperature | |
| Infrared or Convection (20 sec.) | 235°C |

Operating Ratings (Note 1)

| Supply Voltage | 2V to 5V |
|------------------------------------|---------------|
| Operating Temperature Range | –40°C to 85°C |
| Thermal Resistance (θ_{JA}) | 368°C/W |

2.2V Electrical Characteristics (Note 3)

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V_{DD} = 2.2V$, $V_{IN} = 18 \text{ mV}_{PP}$, $R_L = 2.2 \text{ k}\Omega$ and $C = 2.2 \text{ \mu}F$. **Boldface** limits apply at the temperature extremes.

| | | | | Min | Тур | Max | |
|-------------------|-------------------------------|---|------------|----------|----------|----------|-------|
| Symbol | Parameter | Conditions | | (Note 4) | (Note 5) | (Note 4) | Units |
| I _{DD} | Supply Current | V _{IN} = GND | LMV1015-15 | | 180 | 300 | |
| | | | | | | 325 | |
| | | | LMV1015-25 | | 141 | 250 | μΑ |
| | | | | | | 300 | |
| SNR | Signal to Noise Ratio | f = 1 kHz, | LMV1015-15 | | 60 | | |
| | | V _{IN} = 18 mV _{PP} , A-Weighted | LMV1015-25 | | 61 | | dB |
| V _{IN} | Max Input Signal | f = 1 kHz and | LMV1015-15 | | 100 | | m\/ |
| | | THD+N < 1% | LMV1015-25 | | 28 | | |
| V _{OUT} | Output Voltage | V _{IN} = GND | LMV1015-15 | 1.54 | 1.81 | 1.94 | |
| | | | | 1.48 | | 2.00 | V |
| | | | LMV1015-25 | 1.65 | 1.90 | 2.02 | v |
| | | | | 1.49 | | 2.18 | |
| f _{LOW} | Lower –3dB Roll Off Frequency | $R_{SOURCE} = 50\Omega$ | | | 65 | | Hz |
| f _{HIGH} | Upper –3dB Roll Off Frequency | $R_{SOURCE} = 50\Omega$ | | | 95 | | kHz |
| e _n | Output Noise | A-Weighted | LMV1015-15 | | -89 | | |
| | | | LMV1015-25 | | -82 | | uвv |
| THD | Total Harmonic Distortion | f = 1 kHz, | LMV1015-15 | | 0.09 | | 0/ |
| | | $V_{IN} = 18 \text{ mV}_{PP}$ | LMV1015-25 | | 0.15 | | % |
| CIN | Input Capacitance | | | | 2 | | pF |
| Z _{IN} | Input Impedance | | | | >1000 | | GΩ |
| A _V | Gain | f = 1 kHz, | LMV1015-15 | 14.0 | 15.6 | 16.9 | |
| | | $R_{SOURCE} = 50\Omega$ | | 13.1 | | 17.5 | dB |
| | | | LMV1015-25 | 22.5 | 23.8 | 25.0 | UD |
| | | | | 21.4 | | 25.7 | |

5V Electrical Characteristics (Note 3)

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V_{DD} = 5V$, $V_{IN} = 18 \text{ mV}_{PP}$, $R_L = 2.2 \text{ k}\Omega$ and $C = 2.2 \mu F$. **Boldface** limits apply at the temperature extremes.

| | | | | Min | Тур | Max | |
|-----------------|----------------|-----------------------|------------|----------|----------|----------|-------|
| Symbol | Parameter | Conditions | | (Note 4) | (Note 5) | (Note 4) | Units |
| I _{DD} | Supply Current | V _{IN} = GND | LMV1015-15 | | 200 | 300 | |
| | | | | | | 325 | |
| | | | LMV1015-25 | | 160 | 250 | μΑ |
| | | | | | | 300 | |
| | | • | • | | | | |

| Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}$ C, $V_{DD} = 5$ V, $V_{IN} = 18 \text{ mV}_{PP}$, $R_L = 2.2 \text{ k}\Omega$ and C = 2.2 μ F. Boldface limits apply at the temperature extremes. | | | | | | | |
|--|-------------------------------|--|------------|-----------------|-----------------|-----------------|--------------------|
| Symbol | Parameter | Conditions | | Min (Note 4) | Typ (Note 5) | Max (Note 4) | Units |
| SNR | Signal to Noise Ratio | $ f = 1 \text{ kHz}, \\ V_{IN} = 18 \text{ mV}_{PP}, \\ \text{A-Weighted} $ | LMV1015-15 | | 60 | | dB |
| | | | LMV1015-25 | | 61 | | |
| V _{IN} | Max Input Signal | f = 1 kHz and | LMV1015-15 | | 100 | | mV |
| | | THD+N < 1% | LMV1015-25 | | 28 | | IIIV _{PP} |
| V _{OUT} | Output Voltage | V _{IN} = GND | LMV1015-15 | 4.34 | 4.56 | 4.74 | |
| | | | | 4.28 | | 4.80 | V |
| | | | LMV1015-25 | 4.45 | 4.65 | 4.83 | v |
| | | | | 4.39 | | 4.86 | |
| f _{LOW} | Lower –3dB Roll Off Frequency | $R_{SOURCE} = 50\Omega$ | | | 67 | | Hz |
| f _{HIGH} | Upper –3dB Roll Off Frequency | $R_{SOURCE} = 50\Omega$ | | | 150 | | kHz |
| e _n | Output Noise | A-Weighted | LMV1015-15 | | -89 | | dBV |
| | | | LMV1015-25 | | -82 | | uвv |
| THD | Total Harmonic Distortion | f = 1 kHz, | LMV1015-15 | | 0.13 | | 0/ |
| | | $V_{IN} = 18 \text{ mV}_{PP}$ | LMV1015-25 | | 0.21 | | 70 |
| CIN | Input Capacitance | | | | 2 | | pF |
| Z _{IN} | Input Impedance | | | | >1000 | | GΩ |
| A _V | Gain | f = 1 kHz, | LMV1015-15 | 14.0 | 15.6 | 16.9 | |
| | | $R_{SOURCE} = 50\Omega$ | | 13.1 | | 17.5 | dD |
| | | | LMV1015-25 | 22.5 | 23.9 | 25.1 | чD |
| | | | | 21.2 | | 25.9 | |

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics. **Note 2:** Human Body Model (HBM) is $1.5 \text{ k}\Omega$ in series with 100 pF.

Note 3: Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

Note 4: All limits are guaranteed by design or statistical analysis.

5V Electrical Characteristics (Note 3) (Continued)

Note 5: Typical values represent the most likely parametric norm.

Note 6: The maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

LMV1015 Analog Series

Connection Diagram



Large Dome 4-Bump micro SMD

Note: - Pin numbers are referenced to package marking text orientation. - The actual physical placement of the package marking will vary slightly from part to part. The package will designate the date code and will vary considerably. Package marking does not correlate to device type in any way.

Ordering Information

| Dookogo | Dort Number | Dookogo Morking | Transport Madia | | |
|---|------------------------------|------------------------|-------------------------|-------------|--|
| Раскаде | Part Number | Раскаде магкінд | Transport Media | NSC Drawing | |
| 4-Bump Extreme Thin | LMV1015XR-15 | | 250 Units Tape and Reel | | |
| micro SMD LMV1015XRX-15 (0.3 mm max height) LMV1015XR-25 Date Code | LMV1015XRX-15 | Data Cada | 3k Units Tape and Reel | | |
| | 250 Units Tape and Reel | | | | |
| lead free only | lead free only LMV1015XRX-25 | 3k Units Tape and Reel | | | |
| 4-Bump Ultra-Thin | LMV1015UR-15 | | 250 Units Tape and Reel | | |
| micro SMD (0.4 mm max height) lead free only | LMV1015URX-15 | Data Cada | 3k Units Tape and Reel | - URA04ADA | |
| | LMV1015UR-25 | Dale Code | 250 Units Tape and Reel | | |
| | LMV1015URX-25 | | 3k Units Tape and Reel | | |

Note: All packages are supplied with large dome bump technology for 1kg adhesion criteria.

LMV1015 Analog Series

Typical Performance Characteristics Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2 \text{ k}\Omega$, $C = 2.2 \text{ }\mu\text{F}$, single supply, $T_A = 25^{\circ}\text{C}$

Supply Current vs. Supply Voltage (LMV1015-15)



Gain and Phase vs. Frequency (LMV1015-15)



Total Harmonic Distortion vs. Frequency (LMV1015-15)





Gain and Phase vs. Frequency (LMV1015-25)



Total Harmonic Distortion vs. Frequency (LMV1015-25)



Supply Current vs. Supply Voltage (LMV1015-25)



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Application Section

HIGH GAIN

The LMV1015 series provides outstanding gain versus the JFET and still maintains the same ease of implementation, with improved gain, linearity and temperature stability. A high gain eliminates the need for extra external components.

BUILT IN GAIN

The LMV1015 is offered in 0.3 mm height space saving small 4-pin micro SMD packages in order to fit inside the different size ECM canisters of a microphone. The LMV1015 is placed on the PCB inside the microphone using Large Dome Bump technology (LDB).

The bottom side of the PCB usually shows a bull's eye pattern where the outer ring, which is shorted to the metal can, should be connected to the ground. The center dot on the PCB is connected to the V_{DD} through a resistor. This phantom biasing allows both supply voltage and output signal on one connection.





A-WEIGHTED FILTER

The human ear has a frequency range from 20 Hz to about 20 kHz. Within this range the sensitivity of the human ear is not equal for each frequency. To approach the hearing response weighting filters are introduced. One of those filters is the A-weighted filter.

The A-weighted filter is usually used in signal to noise ratio measurements, where sound is compared to device noise. This filter improves the correlation of the measured data to the signal to noise ratio perceived by the human ear.



FIGURE 2. A-Weighted Filter

MEASURING NOISE AND SNR

The overall noise of the LMV1015 is measured within the frequency band from 10 Hz to 22 kHz using an A-weighted filter. The input of the LMV1015 is connected to ground with a 5 pF capacitor, as in *Figure 3*. Special precautions in the internal structure of the LMV1015 have been taken to reduce the noise on the output.



FIGURE 3. Noise Measurement Setup

The signal to noise ratio (SNR) is measured with a 1 kHz input signal of 18 mV_{PP} using an A-weighted filter. This represents a sound pressure level of 94 dB SPL. No input capacitor is connected for the measurement.

SOUND PRESSURE LEVEL

The volume of sound applied to a microphone is usually stated as a pressure level referred to the threshold of hearing of the human ear. The sound pressure level (SPL) in decibels is defined by:

Sound pressure level (dB) = 20 log P_m/P_O

Where,

 P_{m} is the measured sound pressure

 P_{O} is the threshold of hearing (20 $\mu\mathsf{Pa})$

In order to be able to calculate the resulting output voltage of the microphone for a given SPL, the sound pressure in dB

Application Section (Continued)

SPL needs to be converted to the absolute sound pressure in dBPa. This is the sound pressure level in decibels referred to 1 Pascal (Pa).

The conversion is given by:

- dBPa = dB SPL + 20*log 20 µPa
- dBPa = dB SPL 94 dB

Translation from absolute sound pressure level to a voltage is specified by the sensitivity of the microphone. A conventional microphone has a sensitivity of -44 dBV/Pa.



FIGURE 4. dB SPL to dBV Conversion

Example: Busy traffic is 70 dB SPL

 $V_{OUT} = 70 - 94 - 44 = -68 \text{ dBV}$

This is equivalent to 1.13 mV_{PP}

Since the LMV1015-15 has a gain of 6 (15.6 dB) over the JFET, the output voltage of the microphone is 6.78 mV_{PP}. By implementing the LMV1015-15, the sensitivity of the microphone is -28.4 dBV/Pa (-44 + 15.6).

LOW FREQUENCY CUT OFF FILTER

To reduce noise on the output of the microphone a low frequency cut off filter has been implemented. This filter reduces the effect of wind and handling noise.

It's also helpful to reduce the proximity effect in directional microphones. This effect occurs when the sound source is very close to the microphone. The lower frequencies are amplified which gives a bass sound. This amplification can cause an overload, which results in a distortion of the signal.



FIGURE 5. LMV1015-15 Gain vs. Frequency Over Temperature

The LMV1015 is optimized to be used in audio band applications. By using the LMV1015, the gain response is flat within the audio band and has linearity and temperature stability *Figure 5*.

NOISE

Noise pick-up by a microphone in cell phones is a wellknown problem. A conventional JFET circuit is sensitive for noise pick-up because of its high output impedance, which is usually around 2.2 k Ω .

RF noise is amongst other caused by non-linear behavior. The non-linear behavior of the amplifier at high frequencies, well above the usable bandwidth of the device, causes AMdemodulation of high frequency signals. The AM modulation contained in such signals folds back into the audio band, thereby disturbing the intended microphone signal. The GSM signal of a cell phone is such an AM-modulated signal. The modulation frequency of 216 Hz and its harmonics can be observed in the audio band. This kind of noise is called bumblebee noise.

RF noise caused by a GSM signal can be reduced by connecting two external capacitors to ground, see *Figure 6*. One capacitor reduces the noise caused by the 900 MHz carrier and the other reduces the noise caused by 1800/ 1900 MHz.

Application Section (Continued)







Notes

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